## NSN 5961-01-201-3725

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-201-3725 **Inclosure Material:** Metal **Overall Length:** 0.643 inches **Overall Height:** 0.085 inches **Overall Width:** 0.505 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact-darlington connected **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-base, emitter open and 5.0 emitter to base voltage, static, collector open and 60.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 8.00 amperes source cutoff current and 120.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 2.2 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**